





SPECIFICATION FOR 1.8V LVDS SMT TCXO MtronPTI P/N M6302S030

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions		
Frequency of Operation	Fo		150.000000		MHz			
Frequency Tolerance		-1.0		+1.0	ppm	@ +25°C		
Frequency Stability								
vs. Temperature	Δ F/F			4.6	ppm	(Max-Min)/2		
vs. Aging		-3		+3	ppm	1 st year		
		-1		+1	ppm	Per year thereafter.		
			RF Outpu	t				
Output Type	Differential LVDS Compatible			patible				
Output Load		100 Ω Differential			V			
Common Mode Output Voltage			1.2		V			
Differential Output Voltage		250	425	500	mV	LVDS Load		
Symmetry (duty cycle)	T _{DC}	45		55	%	Referenced to 1.2 V		
Rise/Fall Time	T_R/T_F			0.35	nS	From 20% to 80% Vcc		
	S	upply Vo	Itage & Powe	r Consum	nption			
Operating Voltage	V _{cc}	1.71	1.80	1.89	V			
Operating Current	I _{cc}			100	mA			

Environmental Conditions:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Operating Temperature	T _A	-55		+125	°C	
Storage Temperature	Ts	-55		+125	°C	
Shock	Per MIL-STD-202, Method 213, Condition C (100 g's, 6 ms duration, ½ sinewave)					duration, ½ sinewave)
Vibration	Per MIL-STD-202, Method 201 & 204 (10 g's from 10-2000 Hz)					
Thermal Shock	Per MIL-STD-883, Method 1011, Condition A					
Thermal Cycle	Per MIL-STD-883, Method 1010, Condition B					
Hermeticity	Per MIL-STD-202, Method 112 (1 x 10 ⁻⁸ atm cc/s of helium)					
Moisture Sensitivity Level (MSL)	MSL 1					
Solderability	Per EIAJ-STD-002					
Max. Soldering Conditions	See Figure 1.					
Package Type	6-pad 5.0 X 7.0 X 1.9 mm leadless ceramic. RoHS compliant.					

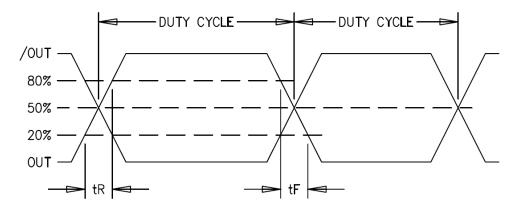




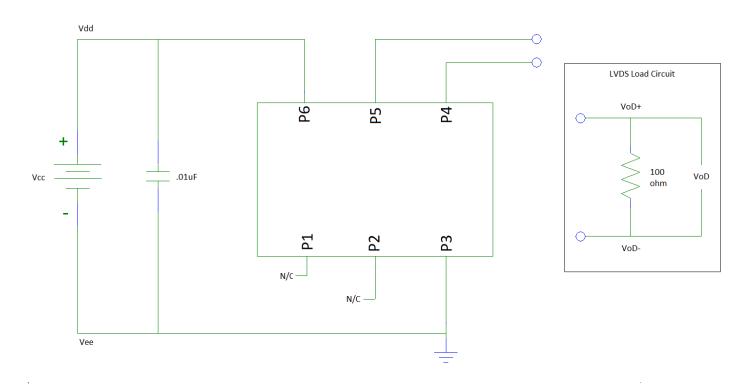


SPECIFICATION FOR 1.8V LVDS SMT TCXO MtronPTI P/N M6302S030

Output Waveform:



Typical Test Circuit & Load Circuit Diagrams:









SPECIFICATION FOR 1.8V LVDS SMT TCXO MtronPTI P/N M6302S030

Soldering Conditions:

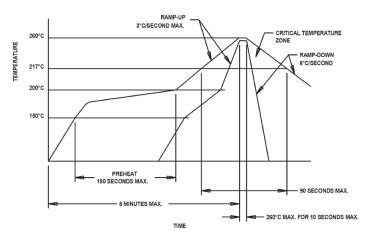
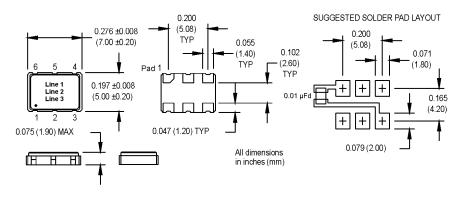


Figure 1

Mechanical, Marking, and Pin Out Information:



Datasheet Revision Table:

Date	Rev.	Author	Details of Revision
01/23/19	0	MM	Original release.